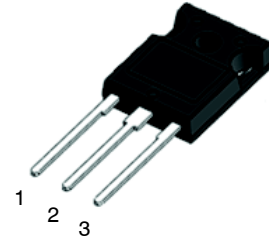


Silicon Carbide (SiC) Schottky Diode – EliteSiC, 30 A, 650 V, D1, TO-247-3L

FFSH3065ADN-F155



TO-247
 LONG LEAD
 CASE 340CH

Description

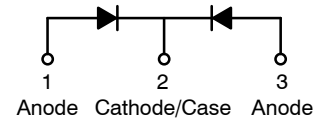
Silicon Carbide (SiC) Schottky Diodes use a completely new technology that provides superior switching performance and higher reliability compared to Silicon. No reverse recovery current, temperature independent switching characteristics, and excellent thermal performance sets Silicon Carbide as the next generation of power semiconductor. System benefits include highest efficiency, faster operating frequency, increased power density, reduced EMI, and reduced system size and cost.

Features

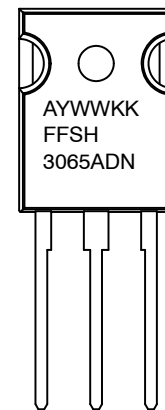
- Max Junction Temperature 175°C
- Avalanche Rated 81 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery/No Forward Recovery
- This Device is Pb-Free, Halogen Free/BFR Free and RoHS Compliant

Applications

- General Purpose
- SMPS, Solar Inverter, UPS
- Power Switching Circuits



MARKING DIAGRAM



- | | |
|-------------|---------------------------|
| A | = Assembly Plant Code |
| YWW | = Date Code (Year & Week) |
| KK | = Lot Traceability Code |
| FFSH3065ADN | = Specific Device Code |

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

FFSH3065ADN-F155

Table 1. ABSOLUTE MAXIMUM RATINGS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

| Symbol | Parameter | Value | Unit | |
|----------------|---|--|------------------|---|
| V_{RRM} | Peak Repetitive Reverse Voltage | 650 | V | |
| E_{AS} | Single Pulse Avalanche Energy (Note 1) | 81 | mJ | |
| I_F | Continuous Rectified Forward Current @ $T_C < 148^\circ\text{C}$ (Note 2) | 16*/30** | A | |
| | Continuous Rectified Forward Current @ $T_C < 135^\circ\text{C}$ | 23*/36** | | |
| $I_{F,Max}$ | Non-Repetitive Peak Forward Surge Current | $T_C = 25^\circ\text{C}$, 10 μs | 1000 | A |
| | | $T_C = 150^\circ\text{C}$, 10 μs | 900 | A |
| $I_{F,SM}$ | Non-Repetitive Forward Surge Current | Half-Sine Pulse, $t_p = 8.3$ ms | 90 | A |
| $I_{F,RM}$ | Repetitive Forward Surge Current | Half-Sine Pulse, $t_p = 8.3$ ms | 50 | A |
| P_{tot} | Power Dissipation | $T_C = 25^\circ\text{C}$ | 165 | W |
| | | $T_C = 150^\circ\text{C}$ | 28 | W |
| T_J, T_{STG} | Operating and Storage Temperature Range | -55 to +175 | $^\circ\text{C}$ | |
| | TO247 Mounting Torque, M3 Screw | 60 | Ncm | |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- E_{AS} of 81 mJ is based on starting $T_J = 25^\circ\text{C}$, $L = 0.5$ mH, $I_{AS} = 18$ A, $V = 50$ V.
- Limited by per device.

Table 2. THERMAL CHARACTERISTICS

| Symbol | Parameter | Rating | Unit |
|-----------------|--|-------------|---------------------------|
| $R_{\theta JC}$ | Thermal Resistance, Junction-to-Case, Max. | 0.91*/0.4** | $^\circ\text{C}/\text{W}$ |

* Per Leg

** Per Device

Table 3. OPERATING CHARACTERISTICS ($T_C = 25^\circ\text{C}$, unless otherwise noted)

| Symbol | Parameter | Test Conditions | Min | Typ | Max | Unit |
|--------|-------------------------|--|-----|------|------|---------------|
| V_F | Forward Voltage | $I_F = 16$ A, $T_C = 25^\circ\text{C}$ | - | 1.5 | 1.75 | V |
| | | $I_F = 16$ A, $T_C = 125^\circ\text{C}$ | - | 1.6 | 2.0 | |
| | | $I_F = 16$ A, $T_C = 175^\circ\text{C}$ | - | 1.72 | 2.4 | |
| I_R | Reverse Current | $V_R = 650$ V, $T_C = 25^\circ\text{C}$ | - | - | 200 | μA |
| | | $V_R = 650$ V, $T_C = 125^\circ\text{C}$ | - | - | 400 | |
| | | $V_R = 650$ V, $T_C = 175^\circ\text{C}$ | - | - | 600 | |
| Q_C | Total Capacitive Charge | $V = 400$ V | - | 52 | - | nC |
| C | Total Capacitance | $V_R = 1$ V, $f = 100$ kHz | - | 887 | - | pF |
| | | $V_R = 200$ V, $f = 100$ kHz | - | 95 | - | |
| | | $V_R = 400$ V, $f = 100$ kHz | - | 72 | - | |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

PART MARKING AND ORDERING INFORMATION

| Part Number | Top Mark | Package | Packing Method | Reel Size | Tape Width | Quantity |
|------------------|-------------|------------------|----------------|-----------|------------|----------|
| FFSH3065ADN-F155 | FFSH3065ADN | TO-247 Long Lead | Tube | N/A | N/A | 30 units |

TYPICAL CHARACTERISTICS ($T_J = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)

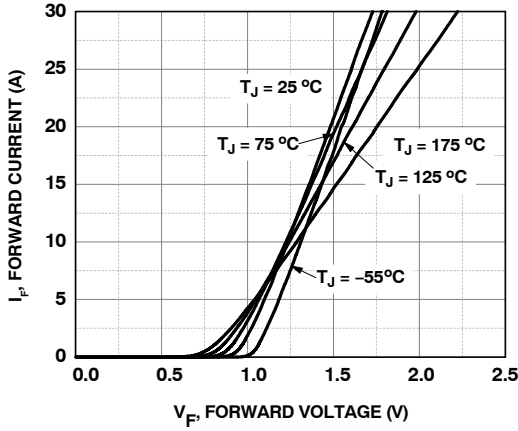


Figure 1. Forward Characteristics

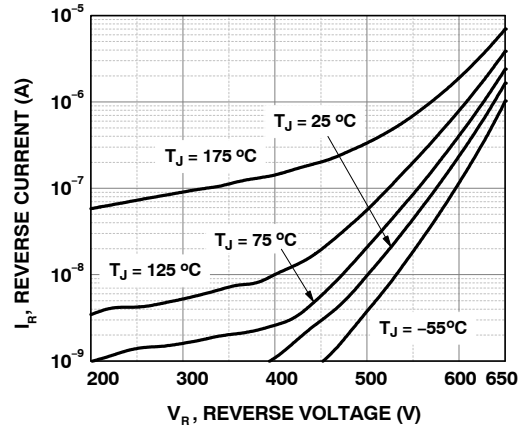


Figure 2. Reverse Characteristics

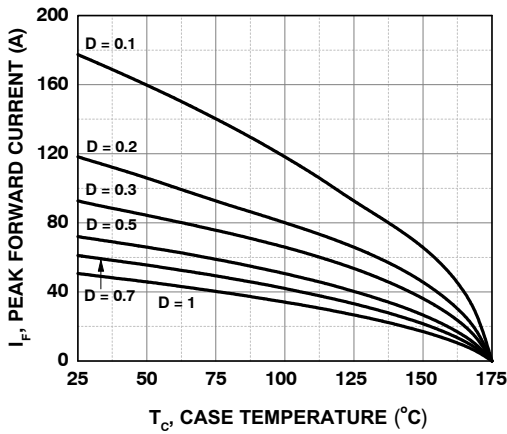


Figure 3. Current Derating

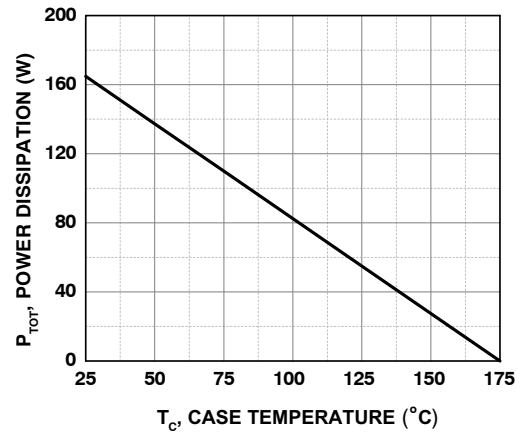


Figure 4. Power Derating

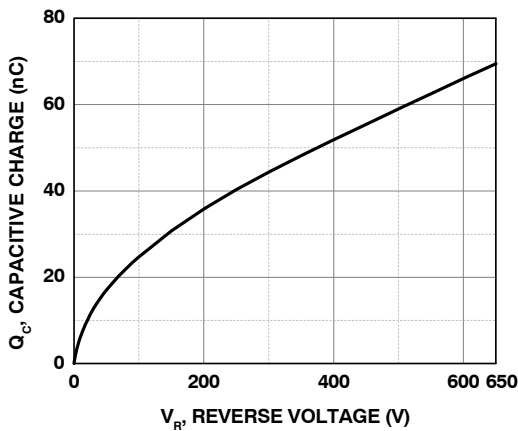


Figure 5. Capacitive Charge vs. Reverse Voltage

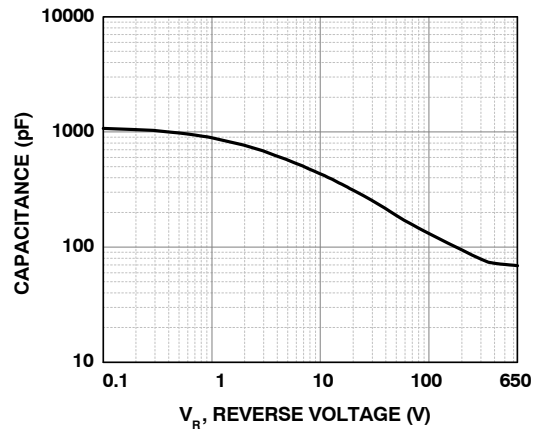


Figure 6. Capacitance vs. Reverse Voltage

TYPICAL CHARACTERISTICS ($T_J = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)

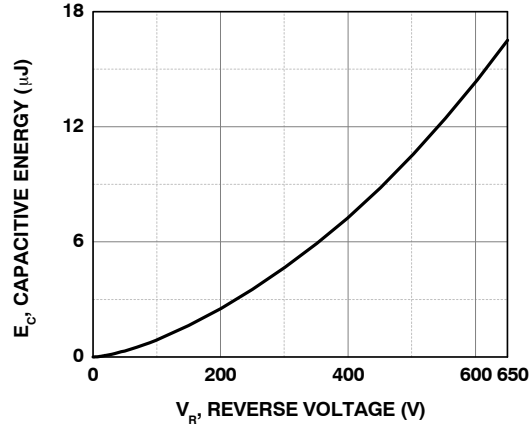


Figure 7. Capacitance Stored Energy

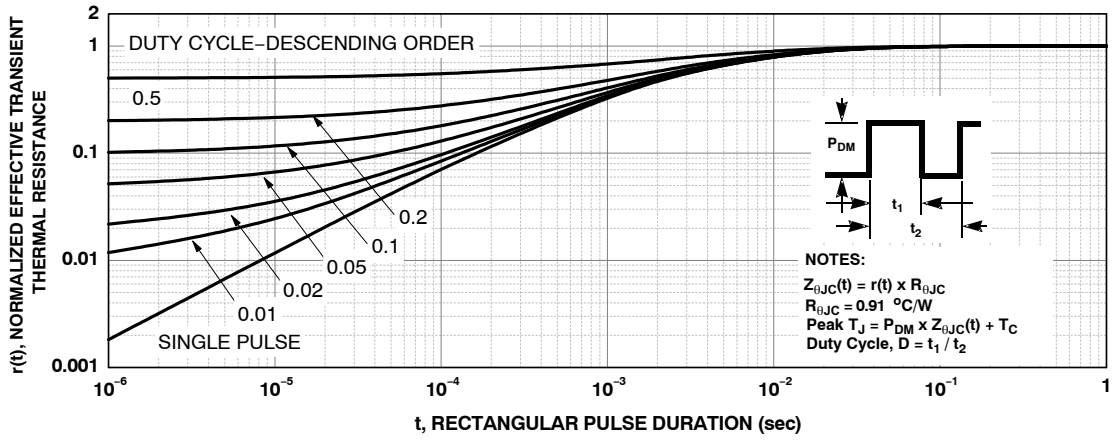


Figure 8. Junction-to-Case Transient Thermal Response Curve

TYPICAL CHARACTERISTICS ($T_J = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)

$L = 0.5\text{mH}$

$R < 0.1\Omega$

$V_{DD} = 50\text{V}$

$E_{AVL} = 1/2LI^2 [V_{R(AVL)}/(V_{R(AVL)} - V_{DD})]$

$Q1 = \text{IGBT } (BV_{CES} > \text{DUT } V_{R(AVL)})$

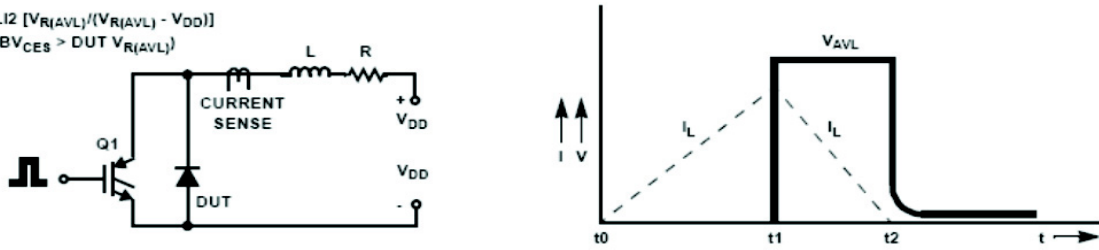


Figure 9. Unclamped Inductive Switching Test Circuit & Waveform

MECHANICAL CASE OUTLINE

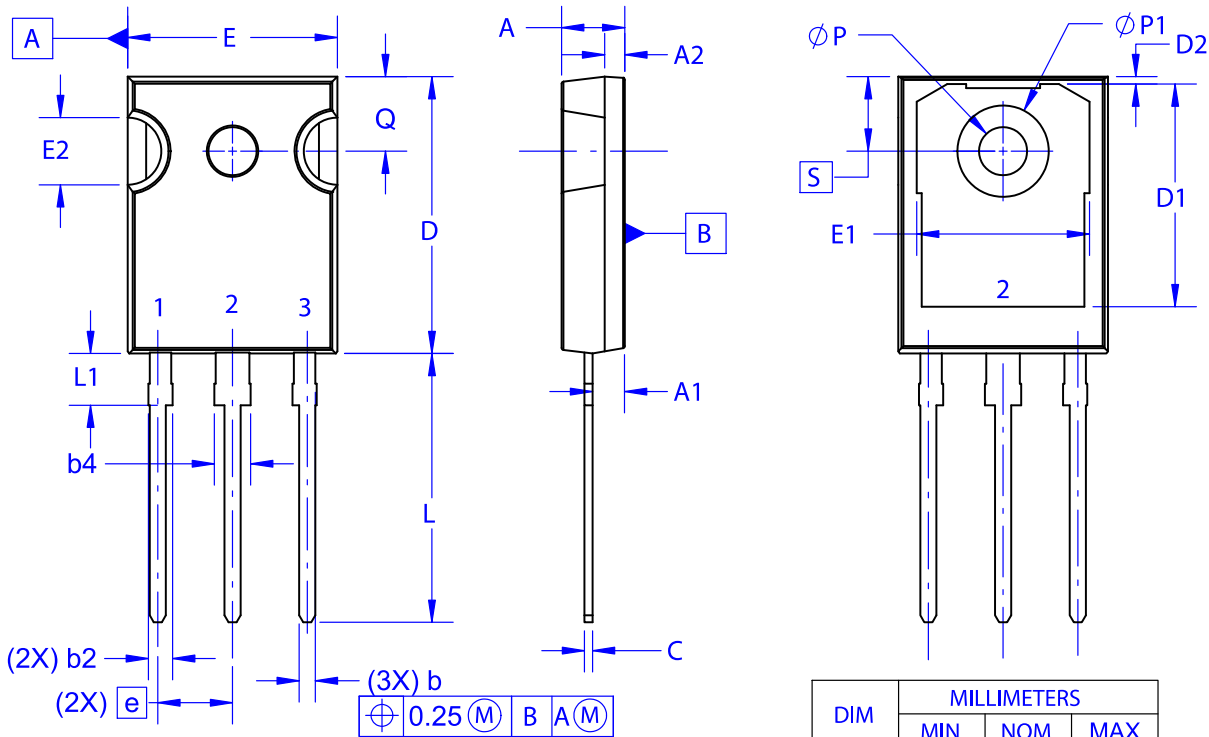
PACKAGE DIMENSIONS

ON Semiconductor®



TO-247-3LD
CASE 340CH
ISSUE A

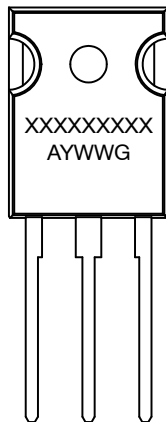
DATE 09 OCT 2019



NOTES: UNLESS OTHERWISE SPECIFIED.

- A. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.
- B. ALL DIMENSIONS ARE IN MILLIMETERS.
- C. DRAWING CONFORMS TO ASME Y14.5 - 2009.
- D. DIMENSION A1 TO BE MEASURED IN THE REGION DEFINED BY L1.
- E. LEAD FINISH IS UNCONTROLLED IN THE REGION DEFINED BY L1.

GENERIC MARKING DIAGRAM*



XXXX = Specific Device Code
A = Assembly Location
Y = Year
WW = Work Week
G = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

| DIM | MILLIMETERS | | |
|-----|-------------|-------|-------|
| | MIN | NOM | MAX |
| A | 4.58 | 4.70 | 4.82 |
| A1 | 2.29 | 2.475 | 2.66 |
| A2 | 1.40 | 1.50 | 1.60 |
| D | 20.32 | 20.57 | 20.82 |
| E | 15.37 | 15.62 | 15.87 |
| E2 | 4.96 | 5.08 | 5.20 |
| e | ~ | 5.56 | ~ |
| L | 19.75 | 20.00 | 20.25 |
| L1 | 3.69 | 3.81 | 3.93 |
| ∅P | 3.51 | 3.58 | 3.65 |
| Q | 5.34 | 5.46 | 5.58 |
| S | 5.34 | 5.46 | 5.58 |
| b | 1.17 | 1.26 | 1.35 |
| b2 | 1.53 | 1.65 | 1.77 |
| b4 | 2.42 | 2.54 | 2.66 |
| c | 0.51 | 0.61 | 0.71 |
| D1 | 13.08 | ~ | ~ |
| D2 | 0.51 | 0.93 | 1.35 |
| E1 | 12.81 | ~ | ~ |
| ∅P1 | 6.61 | 6.73 | 6.85 |

| | | |
|-------------------------|--------------------|---|
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